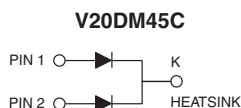
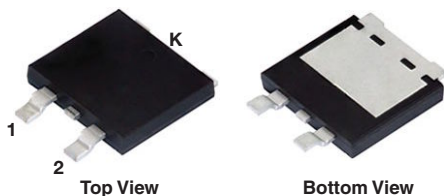


Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.4 \text{ V}$ at $I_F = 5.0 \text{ A}$

TMBS® eSMP® Series SMPD (TO-263AC)



FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
- Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
V_{RRM}	45 V
I_{FSM}	150 A
V_F at $I_F = 10 \text{ A}$ ($T_A = 125 \text{ °C}$)	0.46 V
T_J max.	175 °C
Package	SMPD (TO-263AC)
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V20DM45C	UNIT
Device marking code		V20DM45C	
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$ (1)	20	A
		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	150	A
Operating junction temperature range	T_J (2)	-40 to +175	°C
Storage temperature range	T_{STG}	-55 to +175	

Notes

(1) Mounted on infinite heatsink

(2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.50	-	V
	I _F = 10 A			0.54	0.62	
	I _F = 5 A	T _A = 125 °C		0.40	-	
	I _F = 10 A			0.46	0.54	
Reverse current at rated V _R per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	0.2	mA
		T _A = 125 °C		3	8	
Typical junction capacitance	4.0 V, 1 MHz		C _J	1460	-	pF

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 5\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V20DM45C	UNIT
Typical thermal resistance per device	$R_{\theta JC}^{(1)}$	1.8	$^{\circ}\text{C/W}$
	$R_{\theta JA}^{(2)(3)}$	58	

Notes

- (1) Mounted on infinite heatsink
 (2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$ - junction-to-ambient
 (3) Free air, without heatsink

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V20DM45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
V20DM45CHM3/I ⁽¹⁾	0.55	I	2000/reel	13" diameter plastic tape and reel

Note

- (1) AEC-Q101 qualified

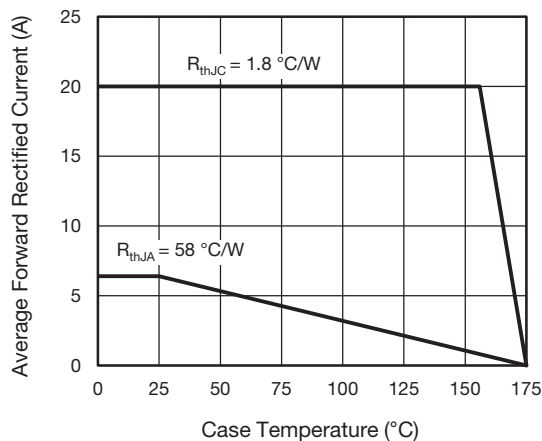
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

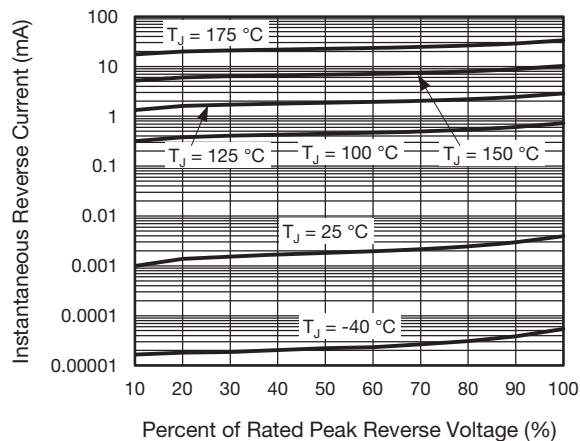


Fig. 4 - Typical Reverse Leakage Characteristics

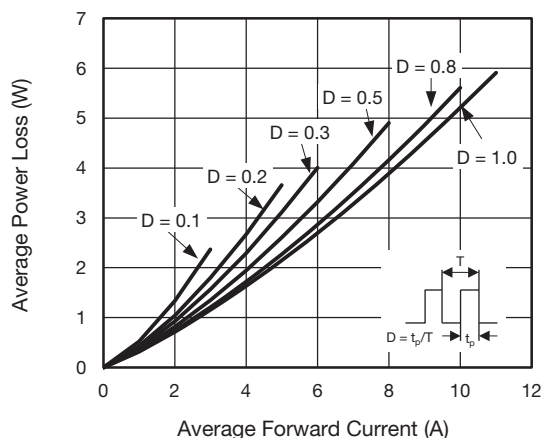


Fig. 2 - Average Power Loss Characteristics

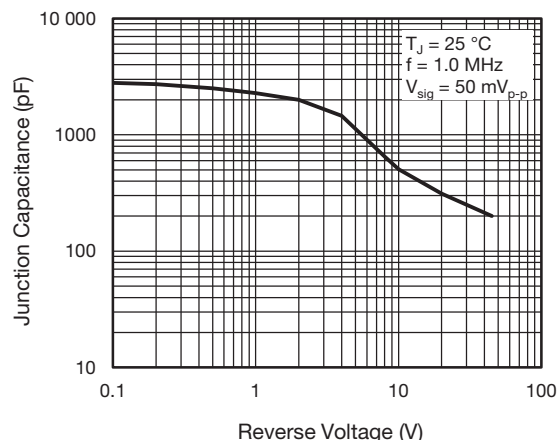


Fig. 5 - Typical Junction Capacitance

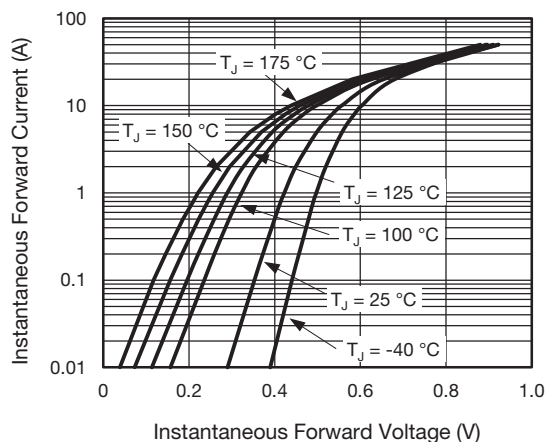


Fig. 3 - Typical Instantaneous Forward Characteristics

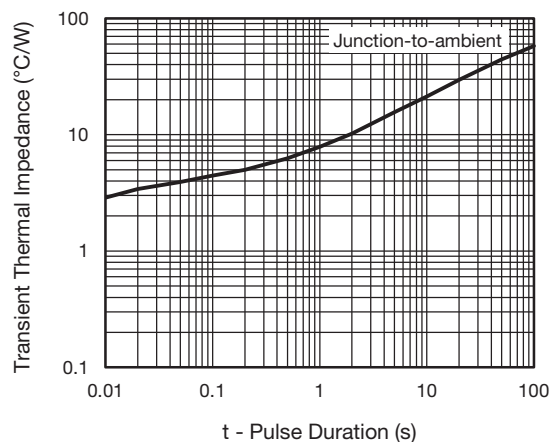


Fig. 6 - Typical Transient Thermal Impedance

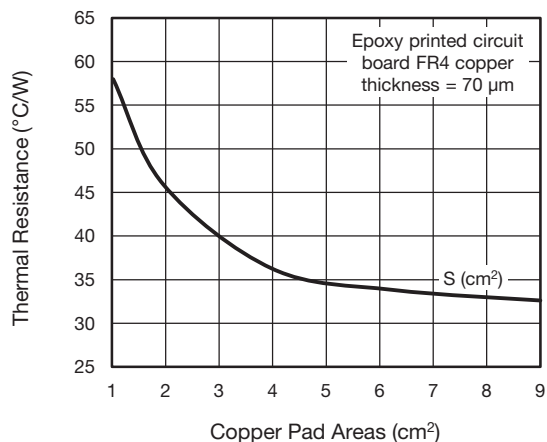
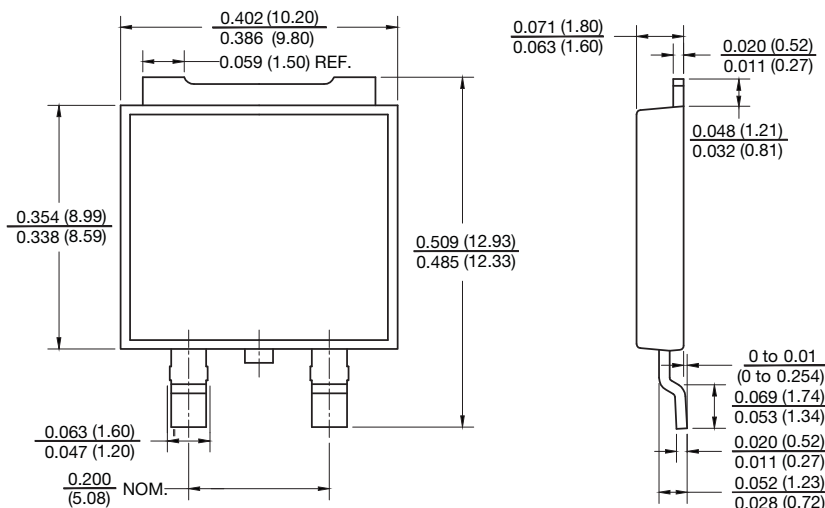


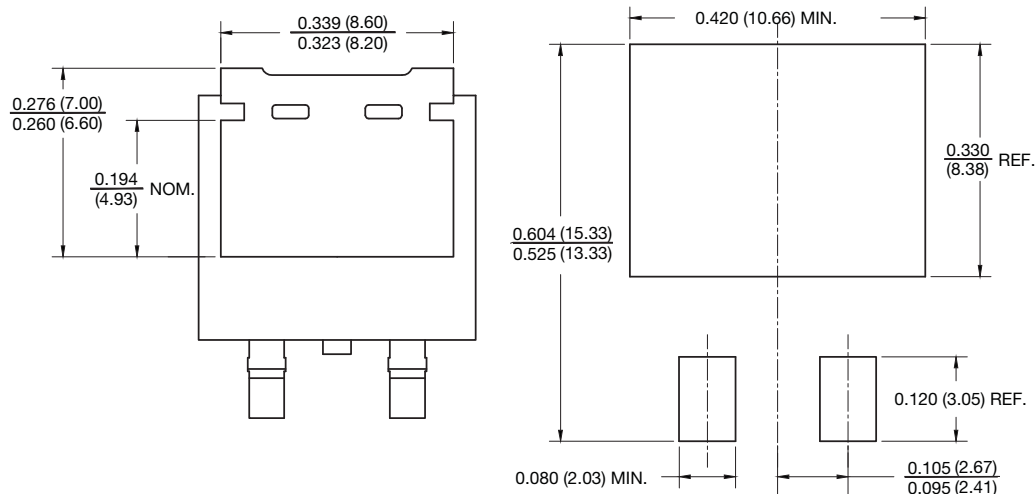
Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMPD (TO-263AC)



Mounting Pad Layout





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